# NSN 5961-00-432-9467

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Inclosure Material:

Metal

**Overall Length:** 

0.375 inches

## **Overall Diameter:**

0.875 inches

# Mounting Facility Quantity:

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

Features Provided:

### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown

voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 7.50 amperes source cutoff current and 25.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

200.0 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnp

### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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